

Table 1 : Mechanism of SPR and schottky barrier of recent studies

Metal/ Semiconductor	Light source	Mechanism
<sup>8</sup> (Pd, Ru, Co, Ni, Fe, Cr)/Bi <sub>2</sub> O <sub>3</sub>	visible	Schottky barrier, leading to an effective charge separation because of the enhanced internal electric field, metal ions behave as microcathodes
<sup>17</sup> Pt–TiO <sub>2</sub> , Au–TiO <sub>2</sub> , Pd–TiO <sub>2</sub>	UV, λ ~254 nm	Schottky barrier, charge transfer from semiconductor to metal
<sup>64</sup> Cu(I)/TiO <sub>2-x</sub>	Infrared	Schottky barrier, Electron supply and partial regeneration of surface oxygen vacancy induced by irradiation
<sup>39</sup> (Rh, Pt, Ru, Ir, Au, Cu or Ni)/TiO <sub>2</sub>	UV, λ ~254 nm	Schottky barrier, an efficient electron trap preventing photogenerated electron-hole recombination, which enhances the efficiency of photocatalytic reaction
<sup>63</sup> CdS–Au–TiO <sub>2</sub> Sandwich Structure	Solar spectrum, visible , λ:525–725 nm	Plasmonic hot electron transfer and back transfer
<sup>61</sup> Au NR/TiO <sub>2</sub>	Visible, λ:508- 610 nm	Schottky junction is established at the interface between the Au NRs and TiO <sub>2</sub> resulting in charge transfer from the TiO <sub>2</sub> to the Au NRs, Illuminating the AuNRs with visible light excited surface plasmons that rapidly decay, producing many hot electrons
<sup>62</sup> AuNRs/TiO <sub>2</sub>	Near-infrared, λ:1000 nm	Plasmon-induced charge excitation, multiple electron holes generated
<sup>33</sup> (CdS@SiO <sub>2</sub> //Au@SiO <sub>2</sub> )	Visible, λ> 350 nm	Localized surface plasmon resonance, locally enhanced electricfield enhance the photoexcitation
<sup>59</sup> Au/CeO <sub>2</sub>	Visible, λ>400nm	Surface plasmon resonance
<sup>38</sup> Au particles on FTO/WO <sub>3</sub> /BiVO <sub>4</sub>	Visible, λ:560 nm	Photoinduced charge separation in a photocatalytic system, without undergoing a plasmon resonance effect
<sup>30</sup> Au/TiO <sub>2</sub>	near-UV, 300< λ> 400 nm	Employs the enhanced electric field amplitude on the surface of Ag NPs in the spectral vicinity of their plasmon resonances
<sup>60</sup> Au–ZnO photoelectrode	Visible, λ:530 nm	Localized plasmon-induced effects and charge separation in photoelectrochemical processes, coupling of hot electrons that are formed by plasmons and the electromagnetic field can effectively increase the probability of a photochemical reaction